

MJ21195 - PNP MJ21196 - NPN

Preferred Devices

Silicon Power Transistors

The MJ21195 and MJ21196 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

Features

- Total Harmonic Distortion Characterized
- High DC Current Gain – $h_{FE} = 25 \text{ Min @ } I_C = 8 \text{ Adc}$
- Excellent Gain Linearity
- High SOA: 3 A, 80 V, 1 Sec
- Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	250	Vdc
Collector-Base Voltage	V_{CBO}	400	Vdc
Emitter-Base Voltage	V_{EBO}	5	Vdc
Collector-Emitter Voltage – 1.5V	V_{CEX}	400	Vdc
Collector Current – Continuous – Peak (Note 1)	I_C	16 30	Adc
Base Current – Continuous	I_B	5	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	250 1.43	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.7	$^\circ\text{C/W}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

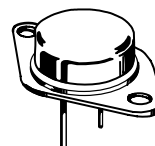
1. Pulse Test: Pulse Width = 5 μs , Duty Cycle $\leq 10\%$.



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**16 AMPERES
COMPLEMENTARY SILICON-
POWER TRANSISTORS
250 VOLTS, 250 WATTS**



TO-204AA (TO-3)
CASE 1-07

MARKING DIAGRAM



MJ2119x = Device Code
x = 5 or 6
G = Pb-Free Package
A = Assembly Location
Y = Year
WW = Work Week
MEX = Country of Origin

ORDERING INFORMATION

Device	Package	Shipping
MJ21195	TO-204	100 Units / Tray
MJ21195G	TO-204 (Pb-Free)	100 Units / Tray
MJ21196	TO-204	100 Units / Tray
MJ21196G	TO-204 (Pb-Free)	100 Units / Tray

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C} \pm 5^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage ($I_C = 100\text{ mA}$, $I_B = 0$)	$V_{CEO(sus)}$	250	–	–	Vdc
Collector Cutoff Current ($V_{CE} = 200\text{ Vdc}$, $I_B = 0$)	I_{CEO}	–	–	100	μAdc
Emitter Cutoff Current ($V_{CE} = 5\text{ Vdc}$, $I_C = 0$)	I_{EBO}	–	–	100	μAdc
Collector Cutoff Current ($V_{CE} = 250\text{ Vdc}$, $V_{BE(off)} = 1.5\text{ Vdc}$)	I_{CEX}	–	–	100	μAdc
SECOND BREAKDOWN					
Second Breakdown Collector Current with Base Forward Biased ($V_{CE} = 50\text{ Vdc}$, $t = 1\text{ s}$ (non-repetitive)) ($V_{CE} = 80\text{ Vdc}$, $t = 1\text{ s}$ (non-repetitive))	$I_{S/b}$	5 2.5	– –	– –	Adc
ON CHARACTERISTICS					
DC Current Gain ($I_C = 8\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$) ($I_C = 16\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$)	h_{FE}	25 8	– –	75	–
Base–Emitter On Voltage ($I_C = 8\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$)	$V_{BE(on)}$	–	–	2.2	Vdc
Collector–Emitter Saturation Voltage ($I_C = 8\text{ Adc}$, $I_B = 0.8\text{ Adc}$) ($I_C = 16\text{ Adc}$, $I_B = 3.2\text{ Adc}$)	$V_{CE(sat)}$	– –	– –	1.4 4	Vdc
DYNAMIC CHARACTERISTICS					
Total Harmonic Distortion at the Output $V_{RMS} = 28.3\text{ V}$, $f = 1\text{ kHz}$, $P_{LOAD} = 100\text{ W}_{RMS}$ (Matched pair $h_{FE} = 50 @ 5\text{ A}/5\text{ V}$)	T_{HD}	– –	0.8 0.08	– –	%
Current Gain Bandwidth Product ($I_C = 1\text{ Adc}$, $V_{CE} = 10\text{ Vdc}$, $f_{test} = 1\text{ MHz}$)	f_T	4	–	–	MHz
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f_{test} = 1\text{ MHz}$)	C_{ob}	–	–	500	pF

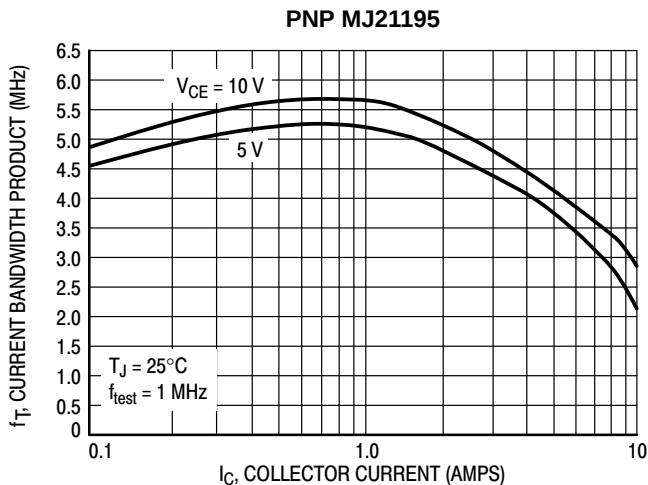
2. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2\%$ 

Figure 1. Typical Current Gain Bandwidth Product

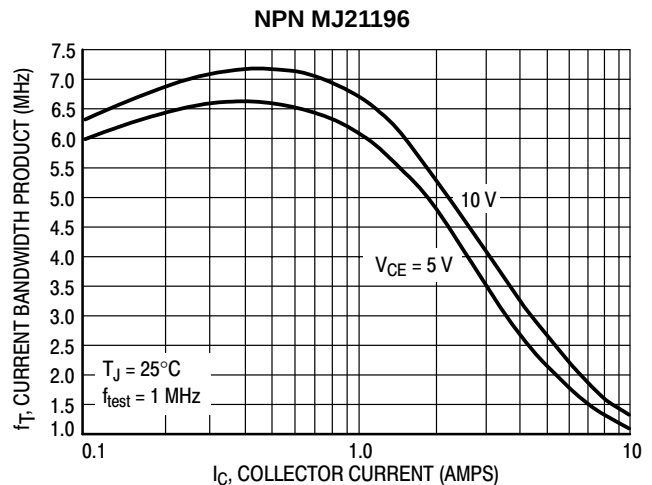


Figure 2. Typical Current Gain Bandwidth Product

TYPICAL CHARACTERISTICS

PNP MJ21195

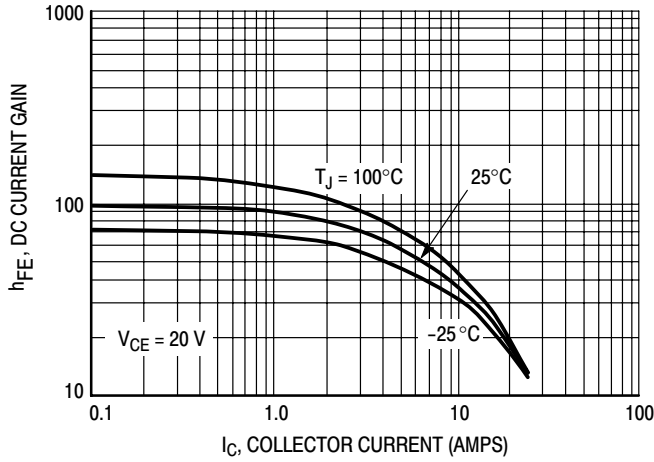


Figure 3. DC Current Gain, $V_{CE} = 20\text{ V}$

NPN MJ21196

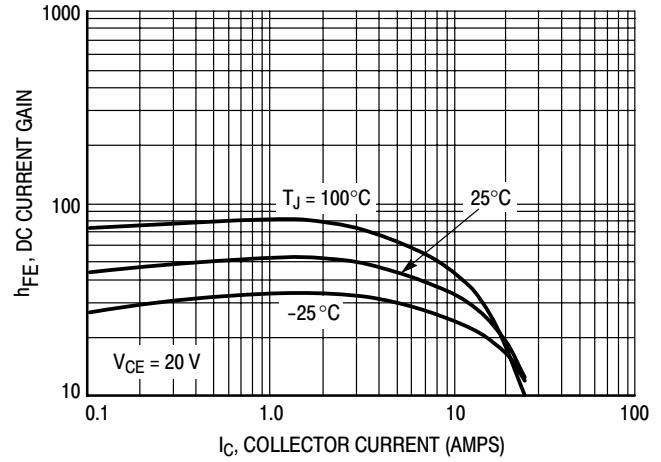


Figure 4. DC Current Gain, $V_{CE} = 20\text{ V}$

PNP MJ21195

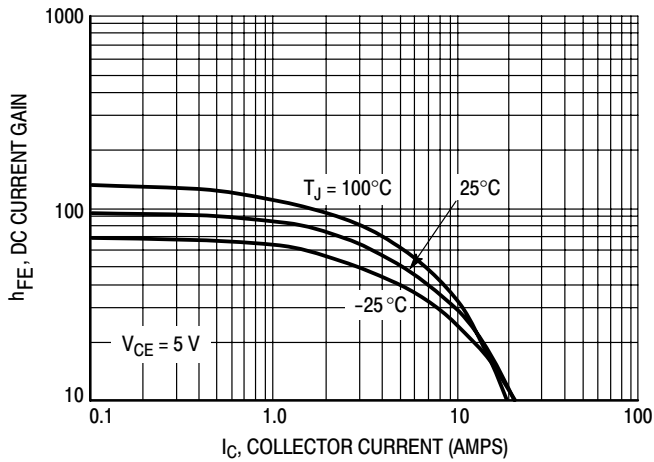


Figure 5. DC Current Gain, $V_{CE} = 5\text{ V}$

NPN MJ21196

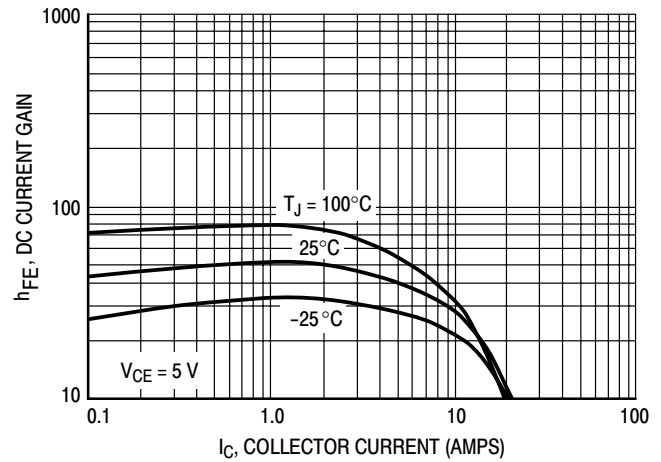


Figure 6. DC Current Gain, $V_{CE} = 5\text{ V}$

PNP MJ21195

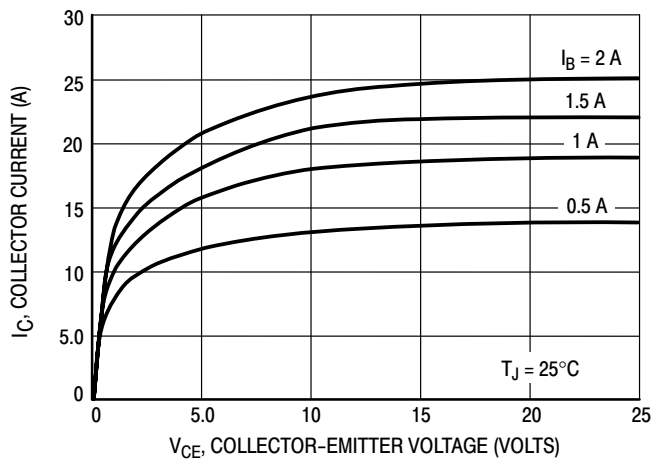


Figure 7. Typical Output Characteristics

NPN MJ21196

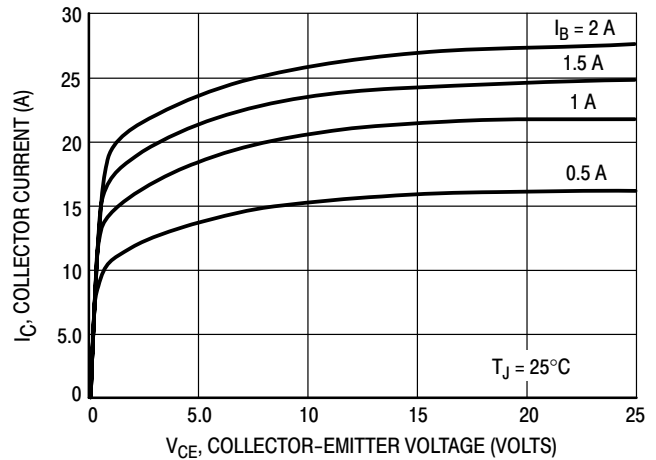


Figure 8. Typical Output Characteristics

TYPICAL CHARACTERISTICS

PNP MJ21195

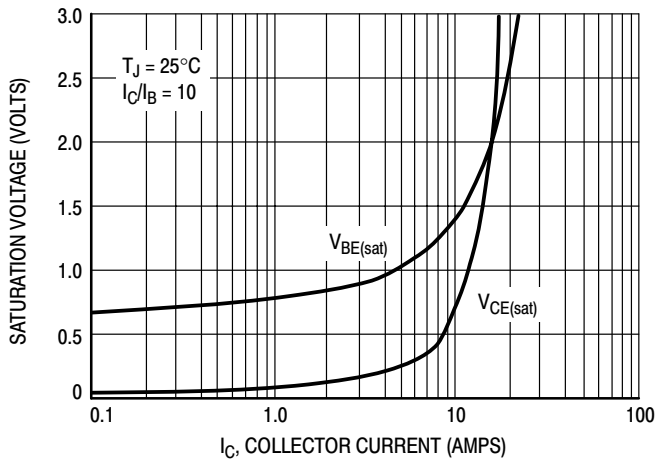


Figure 9. Typical Saturation Voltages

NPN MJ21196

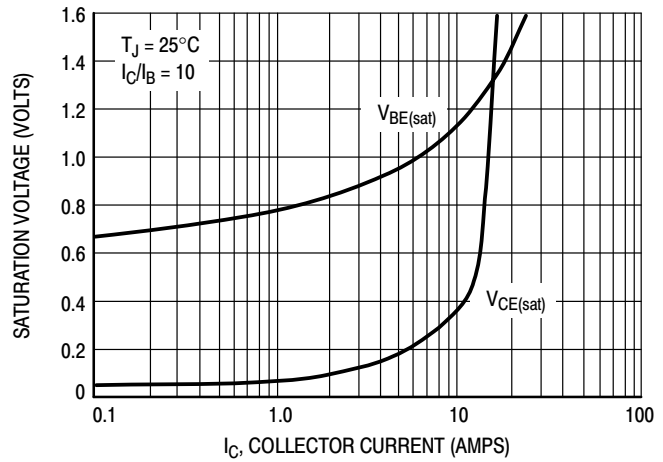


Figure 10. Typical Saturation Voltages

PNP MJ21195

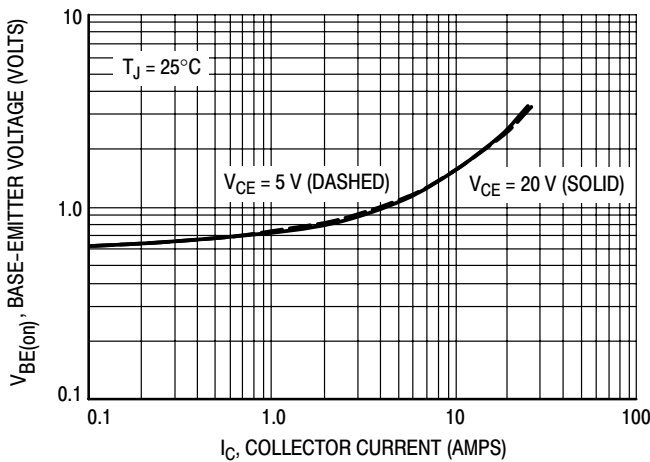


Figure 11. Typical Base-Emitter Voltage

NPN MJ21196

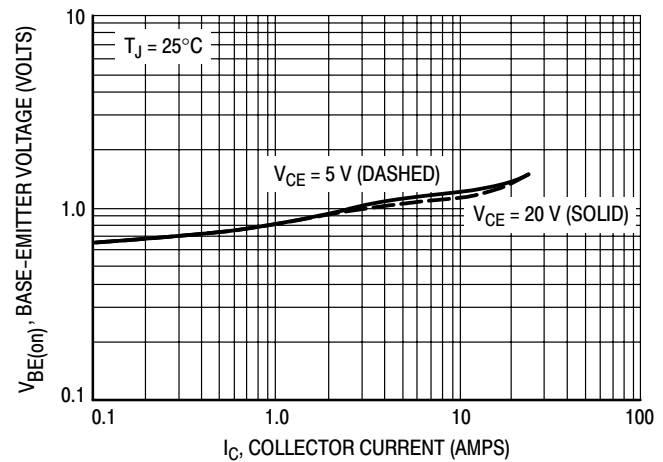


Figure 12. Typical Base-Emitter Voltage

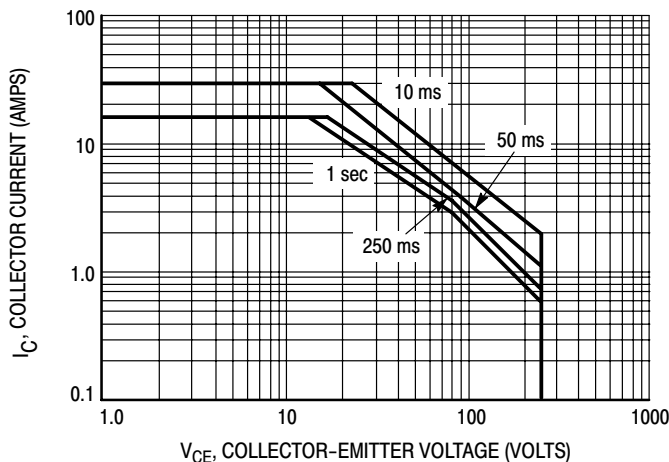


Figure 13. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)} = 200^\circ\text{C}$; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

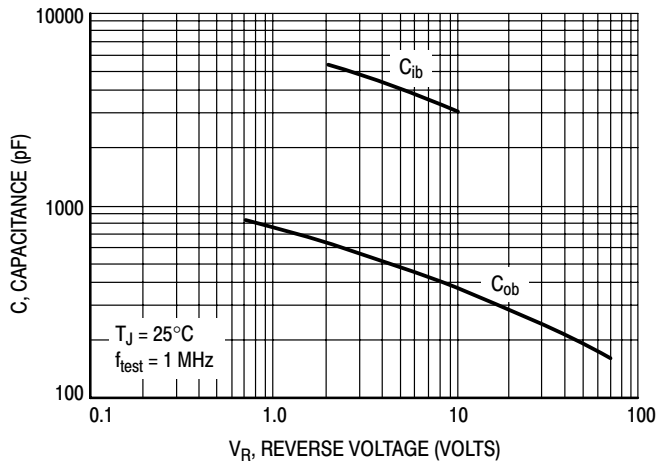


Figure 14. MJ21195 Typical Capacitance

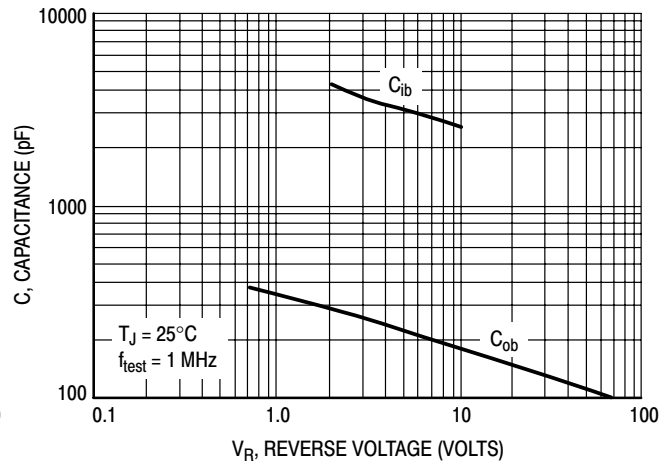


Figure 15. MJ21196 Typical Capacitance

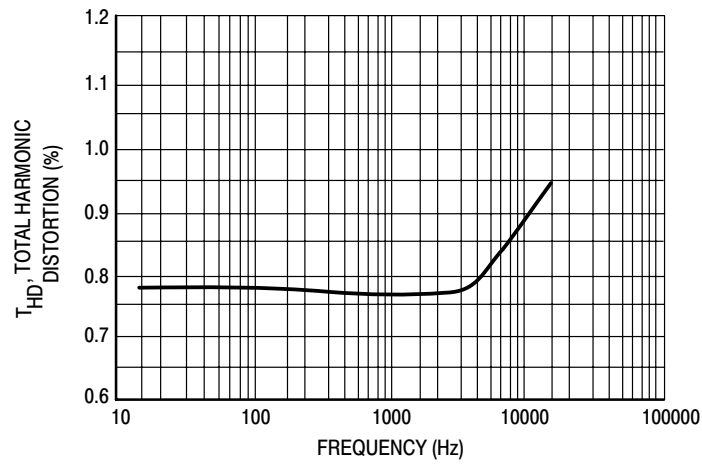


Figure 16. Typical Total Harmonic Distortion

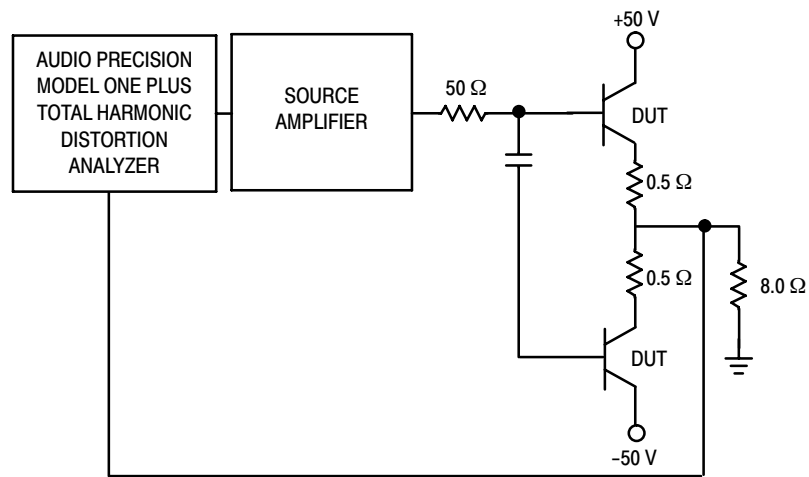
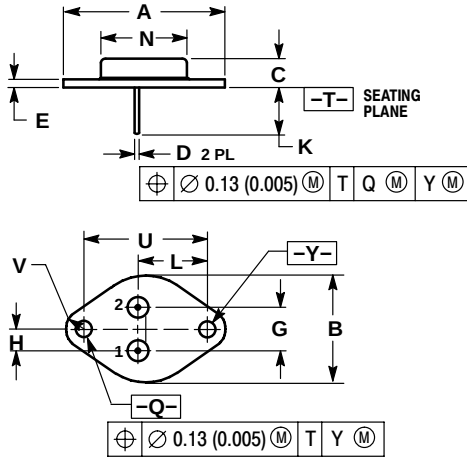


Figure 17. Total Harmonic Distortion Test Circuit

PACKAGE DIMENSIONS

TO-204 (TO-3)
CASE 1-07
ISSUE Z

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF	39.37 REF		
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC	10.92 BSC		
H	0.215 BSC	5.46 BSC		
K	0.440	0.480	11.18	12.19
L	0.665 BSC	16.89 BSC		
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC	30.15 BSC		
V	0.131	0.188	3.33	4.77

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